Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic

Overall Length:

0.300 inches

Terminal Length:

0.975 inches

Overall Diameter:

0.145 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

340.0 regulator voltage

Voltage Tolerance In Percent:

-5.0/+5.0

Current Rating Per Characteristic:

4.00 milliamperes all primaries horsepower metric and 13.00 milliamperes repetitive peak forward current

Power Rating Per Characteristic:

8.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Precious Material And Location:

Terminals or terminal surfaces, options silver

Precious Material:

Silver

Test Data Document:

26916-019-005381 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0